

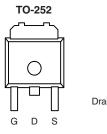
P-Channel 30-V (D-S), MOSFET

| PRODUCT SUMMARY | | | | |
|---------------------|----------------------------------------|---------------------------------|--|--|
| V _{DS} (V) | R_{DS(on)} (Ω) | I _D (A) ^a | | |
| - 30 | 0.010 at V _{GS} = - 10 V | - 15 | | |
| | 0.018 at V _{GS} = - 4.5 V | - 12 | | |

FEATURES

• TrenchFET[®] Power MOSFETs





Drain Connected to Tab



Top View

Ordering Information: SUD45P03-10-E3 (Lead (Pb)-free)

| P-Channel | MOSFET |
|-----------|--------|
| | |

S

| ABSOLUTE MAXIMUM RATINGS $T_A = 25 \text{ °C}$, unless otherwise noted | | | | | | |
|--------------------------------------------------------------------------------|-------------------------|-----------------------------------|----------------|------|--|--|
| Parameter | | Symbol | Limit | Unit | | |
| Drain-Source Voltage | | V _{DS} | - 30 | v | | |
| Gate-Source Voltage | | V _{GS} | ± 20 | | | |
| | T _A = 25 °C | 1_ | - 15 | • | | |
| Continuous Drain Current ^b | T _A = 100 °C | I _D | - 8 | | | |
| Pulsed Drain Current | | I _{DM} | - 100 | A | | |
| Continuous Source Current (Diode Conduction) | | ۱ _S | - 15 | 1 | | |
| Mariana Diata tingh | T _C = 25 °C | P_ | 70 | w | | |
| Maximum Power Dissipation ^b | T _A = 25 °C | P _D | 4 ^b | | | |
| Operating Junction and Storage Temperature Range | | T _J , T _{stg} | - 55 to 150 | °C | | |

| THERMAL RESISTANCE RATINGS | | | | | |
|------------------------------------------|-------------------|---------|---------|------|--|
| Parameter | Symbol | Typical | Maximum | Unit | |
| Maximum Junction-to-Ambient ^b | R _{thJA} | | 30 | °C/W | |
| Maximum Junction-to-Case | R _{thJC} | | 1.8 | 0/10 | |

Notes:

a. Calculated Rating for T_A = 25 °C, for comparison purposes only. This cannot be used as continuous rating (see Absolute Maximum Ratings and Typical Characteristics).

b. Surface Mounted on FR4 board, t \leq 10 s.



SUD45P03-10 P-Channel 30-V (D-S), MOSFET

| Parameter | Symbol | Test Conditions | Min. | Тур. | Max. | Unit |
|-----------------------------------------------|---------------------|-----------------------------------------------------------------------------------------------------|----------|------|-------|------|
| Static | | · | | • | | |
| Drain-Source Breakdown Voltage | V _{DS} | $V_{GS} = 0 V, I_D = -250 \mu A$ | - 30 | | | v |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$ | - 1.0 | | - 3.0 | |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 V, V_{GS} = \pm 20 V$ | | | ± 100 | nA |
| Zara Cata Valtaga Drain Current | | $V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ | | | - 1 | |
| Zero Gate Voltage Drain Current | I _{DSS} | V_{DS} = - 30 V, V_{GS} = 0 V, T_{J} = 125 °C | | | - 50 | μΑ |
| | 1 | V _{DS} = - 5 V, V _{GS} = - 10 V | - 50 | - 50 | | ٨ |
| On-State Drain Current ^a | I _{D(on)} | V _{DS} = - 5 V, V _{GS} = - 4.5 V | - 20 | | | A |
| | | V _{GS} = - 10 V, I _D = - 15 A | | | 0.010 | |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | V_{GS} = - 10 V, I _D = - 15 A, T _J = 125 °C | °C 0.015 | | 0.015 | Ω |
| | | V _{GS} = - 4.5 V, I _D = - 15 A | | | 0.018 | 1 |
| Forward Transconductance ^a | 9 _{fs} | V _{DS} = - 15 V, I _D = - 15 A | 20 | | | S |
| Dynamic ^b | | · · · · | | | | |
| Input Capacitance | C _{iss} | | | 6000 | | pF |
| Output Capacitance | C _{oss} | $V_{GS} = 0 V$, $V_{DS} = -25 V$, f = 1 MHz | | 1100 | | |
| Reverse Transfer Capacitance | C _{rss} |] | | 700 | | |
| Total Gate Charge ^c | Qg | | | 90 | 150 | |
| Gate-Source Charge ^c | Q _{gs} | V_{DS} = - 15 V, V_{GS} = - 10 V, I_{D} = - 45 A | | 20 | | nC |
| Gate-Drain Charge ^c | Q _{gd} | | | 16 | | |
| Turn-On Delay Time ^c | t _{d(on)} | | | 15 | 25 | |
| Rise Time ^c | t _r | V_{DD} = - 15 V, R_L = 0.33 Ω | | 375 | 550 | - ns |
| Turn-Off Delay Time ^c | t _{d(off)} | $\text{I}_\text{D}\cong$ - 45 A, V_GEN = - 10 V, R_G = 2.4 Ω | | 100 | 200 | |
| Fall Time ^c | t _f |] [| | 140 | 250 | |
| Source-Drain Diode Ratings and Cha | racteristic T | _C = 25 °C | | | | |
| Pulsed Current | I _{SM} | | | | 100 | А |
| Diode Forward Voltage ^a | V _{SD} | I _F = - 45 A, V _{GS} = 0 V | | 1.0 | 1.5 | V |
| Source-Drain Reverse Recovery Time | t _{rr} | I _F = - 45 A, dl/dt = 100 A/μs | | 55 | 100 | ns |

Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

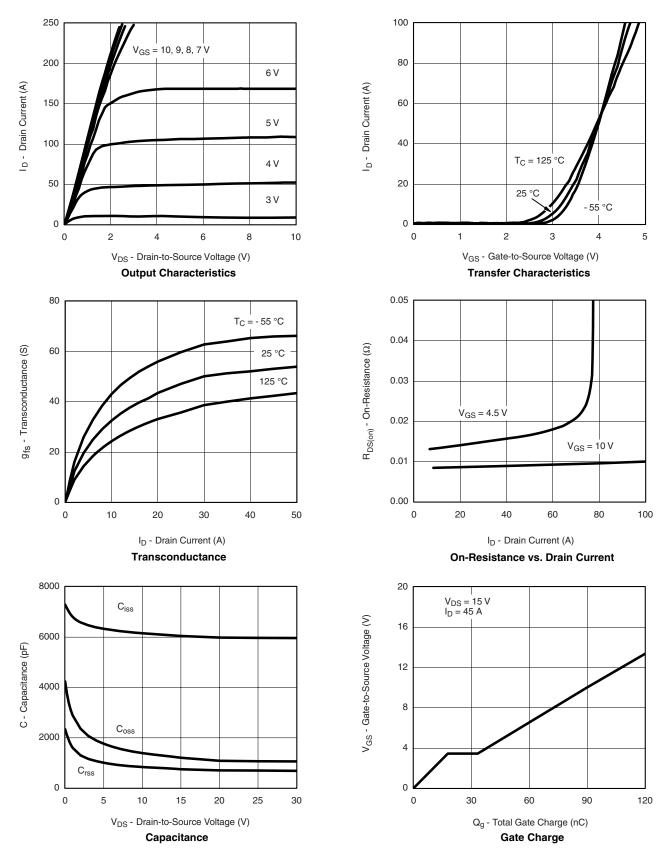
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



SUD45P03-10 P-Channel 30-V (D-S), MOSFET

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





SUD45P03-10 P-Channel 30-V (D-S), MOSFET

T_J = 150 °C

0.6

0.9

V_{SD} - Source-to-Drain Voltage (V)

Source-Drain Diode Forward Voltage

 $T_J = 25 °\dot{C}$

1.2

1.5

100

10

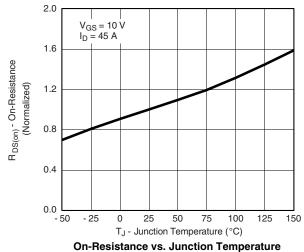
1

0

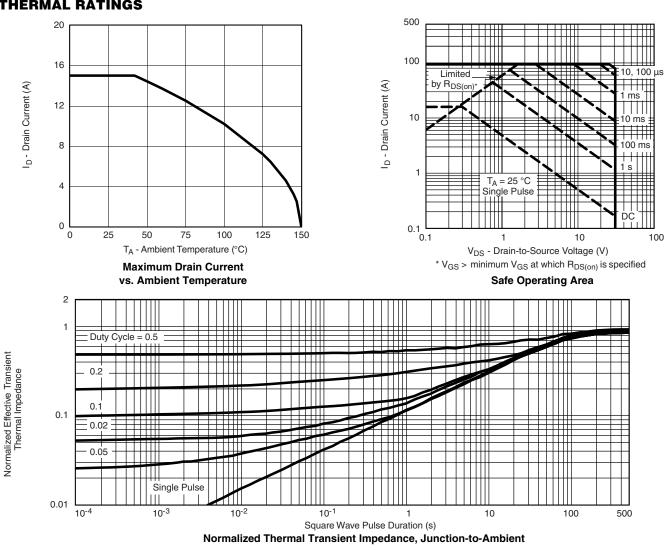
0.3

I_S - Source Current (A)

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



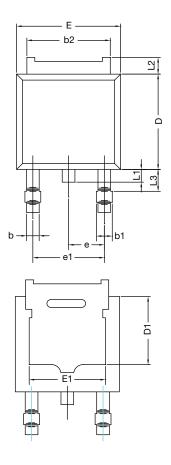


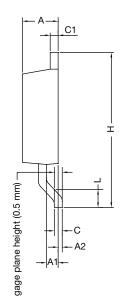




P-Channel 30-V (D-S), MOSFET

TO-252AA CASE OUTLINE





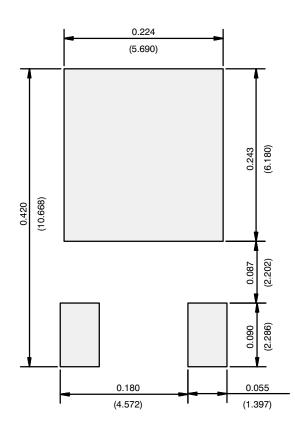
| | MILLIN | IETERS | INCHES | | | |
|----------------------------------------------|--------|--------------------|--------|-------|--|--|
| DIM. | MIN. | MAX. | MIN. | MAX. | | |
| А | 2.21 | 2.38 | 0.087 | 0.094 | | |
| A1 | 0.89 | 1.14 | 0.035 | 0.045 | | |
| A2 | 0.030 | 0.127 | 0.001 | 0.005 | | |
| b | 0.71 | 0.88 | 0.028 | 0.035 | | |
| b1 | 0.76 | 1.14 | 0.030 | 0.045 | | |
| b2 | 5.23 | 5.44 | 0.206 | 0.214 | | |
| С | 0.46 | 0.58 | 0.018 | 0.023 | | |
| C1 | 0.46 | 0.58 | 0.018 | 0.023 | | |
| D | 5.97 | 6.22 | 0.235 | 0.245 | | |
| D1 | 4.10 | 4.45 | 0.161 | 0.175 | | |
| E | 6.48 | 6.73 | 0.255 | 0.265 | | |
| E1 | 4.49 | 5.50 | 0.177 | 0.217 | | |
| е | 2.28 | 2.28 BSC 0.090 BSC | | BSC | | |
| e1 | 4.57 | BSC | 0.180 | BSC | | |
| Н | 9.65 | 10.41 | 0.380 | 0.410 | | |
| L | 1.40 | 1.78 | 0.055 | 0.070 | | |
| L1 | 0.64 | 1.02 | 0.025 | 0.040 | | |
| L2 | 0.89 | 1.27 | 0.035 | 0.050 | | |
| L3 | 1.15 | 1.52 | 0.040 | 0.060 | | |
| ECN: T11-0110-Rev. L, 18-Apr-11 DWG: 5347 | | | | | | |

Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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